



ELECTRONIC COPY

LG785613116
Report verification at igi.org

LABORATORY GROWN DIAMOND REPORT

March 23, 2026
IGI Report Number **LG785613116**
Description **LABORATORY GROWN DIAMOND**
Shape and Cutting Style **SQUARE EMERALD CUT**
Measurements **6.42 X 6.39 X 4.54 MM**

GRADING RESULTS

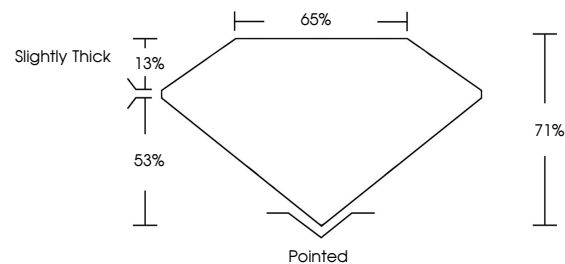
Carat Weight **1.70 CARAT**
Color Grade **D**
Clarity Grade **VVS 2**

ADDITIONAL GRADING INFORMATION

Polish **EXCELLENT**
Symmetry **EXCELLENT**
Fluorescence **NONE**
Inscription(s) **LG785613116**

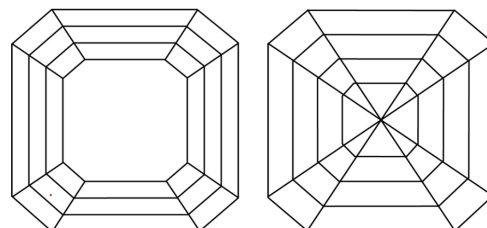
Comments: As Grown - No indication of post-growth treatment.
This Laboratory Grown Diamond was created by High Pressure High Temperature (HPHT) growth process. Type II

PROPORTIONS



Sample Image Used

CLARITY CHARACTERISTICS



KEY TO SYMBOLS

Red symbols indicate internal characteristics.
Green symbols indicate external characteristics.

COLOR

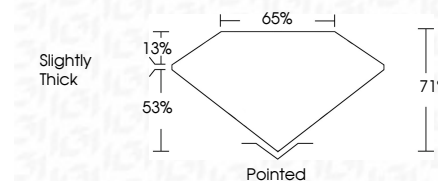
D E F G H I J Faint Very Light Light

CLARITY

FL	IF	VVS ¹⁻²	VS ¹⁻²	SI ¹⁻²	I ¹⁻³
Flawless	Internally Flawless	Very Very Slightly Included	Very Slightly Included	Slightly Included	Included



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IGI Report No **LG785613116**
SQUARE EMERALD CUT
Carat Weight **1.70 CARAT**
Color Grade **D**
Clarity Grade **VVS 2**
Depth **71%**
Table **65%**
Girdle **Slightly Thick**
Culet **Pointed**
Polish **EXCELLENT**
Symmetry **EXCELLENT**
Fluorescence **NONE**
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